








	<p>IPD60R3K3C6</p>
	<p>Hersteller-Teilenummer: IPD60R3K3C6</p> <p>Hersteller / Marke: International Rectifier (Infineon Technologies)</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 1.7A TO252-3</p> <p>Datenblätter:  IPD60R3K3C6.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 54012 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IPD60R3K3C6
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 600V 1.7A TO252-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	54012 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	18.1W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	1.7A (Tc)
Rds On (Max) @ Id, Vgs	3.3 Ohm @ 500mA, 10V
VGS (th) (Max) @ Id	3.5V @ 40µA
Gate Charge (Qg) (Max) @ Vgs	4.6nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	93pF @ 100V
Verpackung	Tape & Reel (TR)

IPD60R3K3C6 ist neu im Original, Suche IPD60R3K3C6 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD60R3K3C6 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD60R3K3C6: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPD60R400CE infineon IPD60R400CE infineon</p>	 <p>IPD60R385CPATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V 9A TO-252</p>	 <p>IPD60R3K3C6ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V 1.7A TO252-3</p>	 <p>IPD60R400CEAUMA1 International Rectifier (Infineon Technologies) CONSUMER</p>
 <p>IPD60R380P6ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V DPAK-3</p>	 <p>IPD60R380P6BTMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V 3TO252</p>	 <p>IPD60R3K4CEAUMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 650V 2.6A TO252-3</p>	 <p>IPD60R400CEATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V TO-252-3</p>

heiße Teile

Mehr

⊗ IPD50P03P4L-04	↔ IPD50P03P4L-11	⇒ IPD50P04P4-13	D IPD50P04P4L-11	↔ IPD50R280CE
⊣ IPD50R380CE	⊗ IPD50R399CP	D IPD50R500CE	⇒ IPD50R520CP	↔ IPD50R650CE
⊗ IPD50R950CE	⊣ IPD530N15N3	⊗ IPD530N15N3G	↔ IPD530N15NG	↔ IPD600N25N3G
D IPD60N10S4L-12	⊗ IPD60R1K0CE	⊣ IPD60R1K4C6	⊗ IPD60R1K5CE	↔ IPD60R2K0C6
⇒ IPD60R360P	↔ IPD60R380C6	⊗ IPD60R380E6	⊣ IPD60R380P6	↔ IPD60R385CP
↔ IPD60R400CE	⇒ IPD60R450E6	D IPD60R520C6	⊗ IPD60R520CP	⊣ IPD60R600C6
⊗ IPD60R600CP	D IPD60R600E6	⇒ IPD60R600P6	↔ IPD60R750E6	↔ IPD60R800CE
⊣ IPD60R950C6	⊗ IPD640N06LG	↔ IPD64CN10NG	⇒ IPD65R1K4C6	↔ IPD65R250C6
⊗ IPD65R250E6	⊣ IPD65R380C6	⊗ IPD65R380E6	D IPD65R420CFD	↔ IPD65R420CFDA
↔ IPD65R600C6	⊗ IPD65R600E6	⊣ IPD65R660CFD	⊗ IPD65R950C6	↔ IPD65R950CFD

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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